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** CONTINUING DATA *****

(None) L1

** FOREIGN APPLICATIONS *****

REPUBLIC OF KOREA 02-76230 12/03/2002

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35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> Met after Allowance				
Verified and Acknowledged <u>Markman</u> Examiner's Signature <u>L1</u> Initials				

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TITLE

Method of forming gate oxide layer in semiconductor devices

FILING FEE RECEIVED 770	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit
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